

Silicon NPN Power Transistors

2SC3907

DESCRIPTION

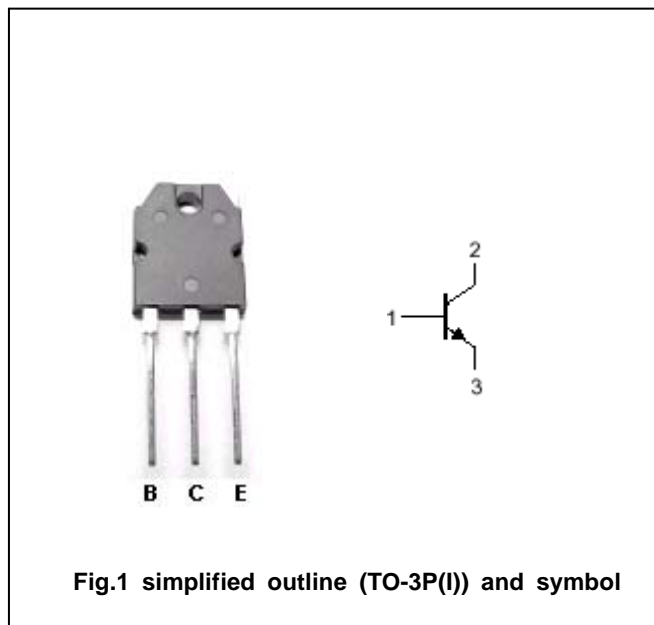
- With TO-3P(I) package
- Complement to type 2SA1516

APPLICATIONS

- Audio and general purpose power amplifier applications
- Recommend for 80W high fidelity audio frequency amplifier output stage

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter



Absolute maximum ratings (Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	180	V
V_{CEO}	Collector-emitter voltage	Open base	180	V
V_{EBO}	Emitter-base voltage	Open collector	5	V
I_C	Collector current		12	A
I_B	Base current		1.2	A
P_C	Collector power dissipation	$T_C=25^\circ\text{C}$	130	W
T_j	Junction temperature		150	$^\circ\text{C}$
T_{stg}	Storage temperature		-55~150	$^\circ\text{C}$

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CHARACTERISTICS

T_j=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =50mA; I _B =0	180			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =8 A; I _B =0.8 A		0.3	2.0	V
V _{BE}	Base-emitter voltage	I _C =7A ; V _{CE} =5V		1.0	1.5	V
I _{CBO}	Collector cut-off current	V _{CB} =180V; I _E =0			5	μ A
I _{EBO}	Emitter cut-off current	V _{EB} =5V; I _C =0			5	μ A
h _{FE-1}	DC current gain	I _C =1A ; V _{CE} =5V	55		180	
h _{FE-2}	DC current gain	I _C =7A ; V _{CE} =5V	35			
f _T	Transition frequency	I _C =1A ; V _{CE} =5V		30		MHz
C _{OB}	Output capacitance	I _E =0; V _{CB} =10V; f=1MHz		270		pF

◆ h_{FE-1} classifications

R	O
55-110	90-180

